

SVETLANA TECHNICAL DATA SV6550C High Performance Audio Beam Power Pentode

he Svetlana[™] SV6550C is a glass envelope beam power pentode. It is intended for ultra linear audio frequency power amplification service. Close manufacturing specification tolerances and improved processing provide improved reliability and superior sonic performance. The new SV6550C features: increased peak cathode emission from new cathode materials; stable operation from extended processing and aging; gold-plated grid; new tri-plate anode; single-piece beam forming electrode; precise grid/screen alignment; improved vacuum processing; and comprehensive static and audio amplifier testing before and after aging.

The Svetlana SV6550C is manufactured in the Svetlana factory in St. Petersburg, Russia, and is designed to be a direct replacement for any 6550.

Characteristics

Electrical

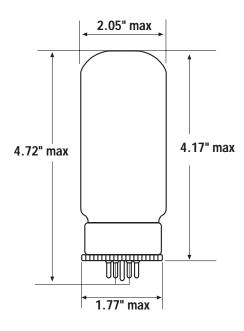
Heater:	Min.	Nom.	Max.		
Voltage (AC or DC)	5.7	6.3	6.9	V	
Current		1.6		Α	
Cathode:		Oxide-c	coated, unipote	ential	
Cathode-to-heater potential, max	К.		-300*/200**	V	
Direct interelectrode capacitance	es, max.***				
Grid no.1 to cathode and grid r	no.3, grid na	o.2,			
base sleeve and heater			18.5	рF	
Plate to cathode and grid no.3,	grid no.2,				
base sleeve and heater			12.5	рF	
Grid no.1 to plate (max)			1.1	рF	
Mechanical					
Operating Position				Any	
· •	Large wafe	r octal 8-pi	n with metal sl	eeve	
Maximum dimensions:					
Height			116 mm (4.5	7 in.)	
Seated height			106 mm (4.17	3 in.)	
Diameter			46 mm (1.8	1 in.)	
Cooling			Convection cooled		
Envelope Temperature (max)			2	50°C	
Approximate net weight			100 g (3.5	5 oz.)	
AF Power Amplifier, Maximur	n ratings				
DC plate voltage			680	V	
Grid no.2 DC (screen) voltage			400	V	
Grid no.1 (control) voltage			-300	V	
DC cathode current			175	mА	
Plate dissipation			35	W	
Grid no.2 (screen) dissipation			6	W	
*Max with heater negative to cath					

**Max with heater positive to cathode

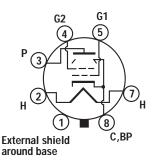
***Without external shielding



Svetlana Outline drawing



Bottom View



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Typical Operation Class A₁ (single tube)

DC plate voltage	400	V
Grid no.2 DC (screen) voltage	225	V
Grid no.1 DC (control) voltage	-22	V
Peak AF grid no.1 (control) voltage	22	V
Zero-signal plate current	87	mА
Max signal plate current	105	mА
Zero signal grid no.2 (screen) current	4	mAdc
Max signal grid no.2 (screen) current	18	mА
Transconductance (nominal)	9500	μS
Load resistance	3000	ohms
Signal output at 5% distortion	12	W

